

Cite this: *Chem. Sci.*, 2025, 16, 7794

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# The scalable growth of high-performance nanostructured heterojunction photoanodes for applications in tandem photoelectrochemical-photovoltaic solar water splitting devices†

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Due to their complementary absorption characteristics and band energy structure, the BiVO<sub>4</sub>-coated WO<sub>3</sub> heterojunction architecture is commonly employed as a metal oxide photoanode for the water oxidation half-reaction. The energy level ordering results in a staggered heterojunction that can effectively separate photoexcited electrons into the WO<sub>3</sub> layer towards the current collector and photoexcited holes into the BiVO<sub>4</sub> layer towards the interface with the electrolyte. Chemical vapour deposition (CVD) is an upscalable technique for fabricating large-area thin films of a wide range of semiconductors with nanoscale control. The fluorine-doped tin oxide (FTO)-coated transparent conductive glass substrates used herein are mass-produced by the glass industry with atmospheric pressure CVD and so the entire photoelectrode could be produced in one production process on float glass panels. This work is a detailed study of the use of atmospheric pressure CVD to fully-fabricate high-performance BiVO<sub>4</sub>-coated WO<sub>3</sub> nanostructures (500–2000 nm in length with 25–100 nm thick BiVO<sub>4</sub> coatings) for photoelectrochemical (PEC) water splitting. Incident photon-to-current efficiency measurements were used to calculate optimal solar predicted photocurrents of 1.92 and 2.61 mA cm<sup>-2</sup> (2.3% and 3.2% solar-to-hydrogen efficiency if coupled to a hypothetical photovoltaic providing 1.23 V) for WO<sub>3</sub>/BiVO<sub>4</sub> heterojunction samples under front and back-illumination, respectively. The heterojunction showed more than additive improvements over the parent materials, with bare WO<sub>3</sub> and BiVO<sub>4</sub> samples showing 0.68 and 0.27 mA cm<sup>-2</sup> and 0.50 and 0.87 mA cm<sup>-2</sup> under front and back-illumination, respectively. Simulations of the current–voltage characteristics of tandem crystalline silicon photovoltaic modules coupled to the PEC devices were consistent with the solar predicted photocurrents. These promising results for BiVO<sub>4</sub>-coated WO<sub>3</sub> nanoneedles fully-deposited by atmospheric pressure CVD enables future research into photoanodes amenable to large-area scale-up.

Received 19th December 2024  
Accepted 22nd March 2025

DOI: 10.1039/d4sc08595g

rsc.li/chemical-science

## 1. Introduction

Technologies that store renewable but intermittent solar energy as a chemical fuel will help society reduce its dependence on fossil fuel extraction. One such technology, photoelectrochemical (PEC) water splitting, uses sunlight to drive the reduction and oxidation of water into hydrogen fuel and oxygen gas at the surfaces of a (photo)cathode and a (photo)anode respectively.<sup>1</sup> PEC water splitting, however, is still an immature

technology, with both laboratory and prototype-scale research underway to improve efficiency, durability, and scalability.<sup>2,3</sup> In contrast to how crystalline Si has become the archetypal low-cost photovoltaic solar cell,<sup>4</sup> no single device design, light absorber nor catalytic material system has emerged as a defining example for efficient, low-cost and scalable PEC water splitting.<sup>5</sup> The Solar Fuels Database<sup>6</sup> collates data on reported PEC water splitting devices. The solar-to-hydrogen (STH) conversion efficiencies for PEC devices made using Si and III–V semiconductors have reached 19%,<sup>7</sup> and the STH conversion efficiencies for devices made using lower-cost, earth-abundant metal oxides have reached ~10%,<sup>6</sup> although only for small-scale devices. Notably, a minimum of 10% is reported as a requirement for the overall performance of PEC water splitting to be comparable to PV-coupled electrolysis,<sup>8</sup> with values as high as 20–26% targeted by the U.S. Department of Energy.<sup>9</sup> Reaching these efficiencies with non-precious materials, whilst also demonstrating acceptable stability, scalability and cost

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† Electronic supplementary information (ESI) available. See DOI: <https://doi.org/10.1039/d4sc08595g>



targets, remains a significant challenge for the PEC water splitting research community.

Si and III–V semiconductor-based devices typically use light absorbers known to be effective in photovoltaic (PV) devices and then add protective passivation layers to prevent their corrosion and promote catalysis in an electrolyte.<sup>10</sup> This method of adding complexity to a traditional PV device is, however, unlikely to be cost-effective compared to PV-coupled electrolysis,<sup>8</sup> which does not have to mitigate the effects of having the electrolyte in close proximity to the light absorbers. Transition metal oxides, in contrast, have higher durability, lower cost, and can be more readily produced using scalable synthesis, and thus are the most commonly studied class of material for PEC water splitting.<sup>2</sup> One limitation to the water splitting performance of metal oxides is their often wide band gaps that can restrict their ability to harvest solar energy.<sup>11</sup> Nevertheless, using multiple distinct light absorbing layers in tandem in a type II heterojunction with staggered conduction and valence bands can enable wider light absorption and maintain efficient transfer of electrons and holes through the layered architecture.<sup>12</sup> The bismuth vanadate-coated tungsten trioxide ( $\text{WO}_3/\text{BiVO}_4$ ) photoanode is one such example of a tandem type II heterojunction.<sup>13</sup>  $\text{WO}_3$  has been shown to have a long hole diffusion length ( $\sim 150$  nm) and good electron mobility ( $\sim 12$  cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>), but suffers from slow charge transfer at the semiconductor/electrolyte interface<sup>14</sup> and can only absorb blue and ultraviolet light with its 2.7–2.8 eV bandgap energy.<sup>15,16</sup>  $\text{BiVO}_4$ , with its indirect bandgap of 2.4 eV,<sup>17</sup> absorbs up to green light, but is hindered by electron–hole recombination and poor charge transport and water oxidation kinetics.<sup>18</sup> Together, however, photocatalysts with a  $\text{WO}_3/\text{BiVO}_4$  sputter-fabricated core–shell architecture, when coupled with a double-junction GaAs/InGaAsP photovoltaic cell, have demonstrated a record 8.1% STH conversion efficiency for  $\text{BiVO}_4$ -based photoanode water splitting devices.<sup>19</sup> This heterojunction configuration of light absorbers benefits from improved charge separation across the interfacial region,<sup>20</sup> while the nanostructuring allows for a simultaneously thick  $\text{BiVO}_4$  layer along the length of the  $\text{WO}_3$  and a radially thin  $\text{BiVO}_4$  layer that mitigates for the poor charge mobility through  $\text{BiVO}_4$ .<sup>21,22</sup> Metal oxide photocathodes, such as those based on  $\text{Cu}_2\text{O}$ , have been demonstrated with up to approximately 7.6 mA cm<sup>-2</sup> or 9.3% STH efficiency when measured at 0 V vs. RHE in a half-cell configuration.<sup>23</sup> The challenge to using photocathodes is that they are typically sensitive to photocorrosion and so require complex capping layers to function. The remainder of this work is focused on photoanodes.

Future commercial PEC water splitting facilities may require photoabsorbers with large areas on the order of centimetres to meters in dimensions.<sup>24</sup> The  $\text{WO}_3/\text{BiVO}_4$  heterojunction photoabsorber literature to date have, however, primarily employed fabrication techniques such as sputtering under vacuum,<sup>25</sup> or electrochemical<sup>26</sup> and spin-coating methods<sup>27,28</sup> that may be difficult to apply to large-area coating. Along with spray pyrolysis,<sup>29,30</sup> chemical vapour deposition (CVD) is a route to making metal oxide thin films that can be scaled to large areas and has been demonstrated to be capable of producing a wide range of inorganic photoabsorbers.<sup>2</sup> Seminal works on water splitting

photocatalysts fabricated by CVD include the vapour transport deposition of  $\text{BiVO}_4$ ,<sup>31</sup> aerosol-assisted chemical vapour deposition (AACVD) of  $\text{BiVO}_4$ ,<sup>32</sup> and demonstration and optimization of  $\text{WO}_3$  nanoneedles by AACVD.<sup>33,34</sup>

This work demonstrates, to our knowledge, the first nanostructured  $\text{WO}_3/\text{BiVO}_4$  heterojunction photoanode where both components are deposited sequentially by AACVD.  $\text{BiVO}_4$  is conformally coated onto  $\text{WO}_3$  nanoneedles on FTO-coated glass to form dense coatings 25–100 nm thick surrounding micron-length, 50–100 nm diameter nanoneedles, as seen by scanning electron microscopy. The characteristic X-ray crystal diffraction, X-ray photoemission spectroscopy, and Raman spectroscopy features for  $\text{WO}_3$  and  $\text{BiVO}_4$  are unchanged when the heterojunction is formed, indicating that each component retains its physical integrity, and that the heterojunction has a distinct interface. Additionally, we also investigate the importance of preventing the aging of the vanadium precursor solution (vanadium(III) acetylacetonate in acetone and methanol), where tests were conducted to help elucidate the mechanism for CVD deposition of  $\text{BiVO}_4$ , adding to the emerging body of knowledge in this field.<sup>35</sup> The  $\text{WO}_3/\text{BiVO}_4$  heterojunction photoanode showed significantly enhanced activity for water oxidation and a superior calculated solar predicted photocurrent (SPP) compared to single component  $\text{WO}_3$  and  $\text{BiVO}_4$  photoanodes, validating the enhanced absorptance properties of the heterojunctions as measured by UV-visible spectroscopy. Modelling of a PV-PEC hybrid device, carried out herein, where a back-illuminated  $\text{WO}_3/\text{BiVO}_4$  heterojunction is coupled to dual crystalline Si PVs placed electrically in series and optically in tandem, estimates that our photoanodes can achieve an unassisted STH of up to 3.4%. Overall, we demonstrate that AACVD can fabricate  $\text{WO}_3/\text{BiVO}_4$  heterojunction photoanodes with promising performance for large-scale device applications.

## 2. Results & discussion

### 2.1 Synthesis of the $\text{WO}_3$ and $\text{BiVO}_4$ photoanodes

A wide range of  $\text{WO}_3$  nanoneedles (NN),  $\text{BiVO}_4$ , and  $\text{BiVO}_4$ -coated  $\text{WO}_3$  samples were fabricated in triplicate and are listed in Table 1 according to their deposition volumes for aerosol-assisted chemical vapour deposition and approximate layer thicknesses determined by side-on scanning electron microscopy (SEM). Fig. S1† shows representative photographs of the post-annealed FTO-glass substrates coated with  $\text{WO}_3$  NN,  $\text{BiVO}_4$ , and  $\text{BiVO}_4$ -coated  $\text{WO}_3$  along with a photograph of the CVD reactor that can deposit samples up to 16 cm × 5 cm in surface area. The FTO-coated substrates used herein are mass-produced by the glass industry with atmospheric pressure CVD<sup>36</sup> and so there is the possibility for the entire photoelectrode to be produced in one production process on float glass panels.  $\text{WO}_3$  films change from a deep blue (substoichiometric  $\text{WO}_{3-x}$ ) to white colour (near stoichiometric  $\text{WO}_3$ ) when annealed in air. Annealing removes trace contaminants, oxidizes the film, and a two-hour annealing time retains optimal  $\sim 2\%$  levels of oxygen vacancies<sup>37</sup> enhancing the photoactivity of the  $\text{WO}_3$  photoanodes.<sup>38,39</sup> Annealing  $\text{BiVO}_4$  films



**Table 1** Combinations of  $\text{WO}_3$  and  $\text{BiVO}_4$  fabricated and studied in triplicate.  $V$  (mL) is the precursor volume (with concentrations of 11.4 mM for  $\text{WO}_3$  and 5 mM for  $\text{BiVO}_4$  precursor solutions) used to produce the layers,  $L$  (nm) is the approximate length of the  $\text{WO}_3$  NN produced, and  $t$  (nm) is the approximate thickness of the  $\text{BiVO}_4$  coating on  $\text{WO}_3$  NN. Tick/cross symbols are used to designate samples that were/were not synthesized, with a total of 22 distinct samples studied herein

			BiVO <sub>4</sub>					V (mL)
			0	5	10	20	40	
			0	12	25	50	100	
WO <sub>3</sub> NN	0	0	X	X	X	✓	✓	
	5	250	✓	✓	✓	✓	✓	
	10	500	✓	✓	✓	✓	✓	
	20	1000	✓	✓	✓	✓	✓	
	40	2000	✓	✓	✓	✓	✓	
	V (mL)	L (nm)						

ensures complete conversion of the films to the more photo-active monoclinic crystal phase<sup>40</sup> and oxidation to yellow  $\text{BiVO}_4$  with  $V$  in the 5+ oxidation state. The rough surface of the  $\text{WO}_3$  NN scatter light and cause the films to appear opaque. The  $\text{BiVO}_4$  on FTO is flat in comparison and appears transparent, while on  $\text{WO}_3$ , the  $\text{BiVO}_4$  coats the NN conformally, so the final heterojunction sample also appears opaque.

**2.1.1 Scanning electron microscopy (SEM) imaging.** SEM imaging (Fig. 1) was conducted to show the morphology of representative heterojunction films. Thicker films made from 80 mL of  $\text{WO}_3$  precursor (11.43 mM  $\text{W}(\text{CO})_6$  dissolved in 3 : 1 acetone and methanol) and 40 mL of  $\text{BiVO}_4$  precursor (5 mM triphenylbismuth and vanadium(III) acetylacetonate dissolved in 3 : 1 acetone and methanol) were fabricated and measured to more easily image the distinct layers on top of the FTO-coated glass substrate, Fig. 1a, in contrast to the thinner layers described in Table 1. Fig. 1b shows the top-down view of  $\text{WO}_3$  NN, which forms as sharp needles (50–100 nm in diameter) growing predominantly upwards in a range of angles. Fig. 1c shows the top-down view of  $\text{WO}_3$  NN that have become more globular upon coating with  $\text{BiVO}_4$ . The final diameter of the  $\text{BiVO}_4$ -coated  $\text{WO}_3$  needles are between 250 and 300 nm, corresponding to a radial coating of about 100 nm, herein referred to as the  $\text{BiVO}_4$  thickness.  $\text{BiVO}_4$  on bare FTO-coated glass, shown from side-on and top-down views in Fig. 1d, coats as a thicker film than on  $\text{WO}_3$  NN; 10 mL precursor solution is used to make the coating in Fig. 1d compared to 40 mL for the coatings in Fig. 1c and f. Fig. 1e and f, which are the side-on images of  $\text{WO}_3$  NN and NN coated with  $\text{BiVO}_4$ , on FTO. The majority of NN are pointing upwards from the FTO. Notably, the AACVD coating process for the  $\text{BiVO}_4$  layer fully penetrates to

the bottom of the host nanostructure, while preserving the needle-structure of the  $\text{WO}_3$ .

## 2.2 Hypothesis for the mechanism of $\text{BiVO}_4$ deposition

Understanding the mechanism for CVD deposition of the ternary  $\text{BiVO}_4$  is important for ensuring high quality depositions. The deposition is more complex than for binary oxides like  $\text{WO}_3$ ,<sup>41</sup> and has not previously been discussed in the literature.<sup>31,32,42,43</sup> In this work, we use thermogravimetric analysis (TGA) and UV-vis of the precursor solutions along with a temperature-dependent X-ray diffraction study to help determine the decomposition dynamics of the  $\text{BiVO}_4$  precursors. The findings enable us to formulate the hypothesis that differences in activation energy between bismuth and vanadium metal-organic precursors leads to controlled product stoichiometry with changing deposition temperature.

TGA in air coupled with mass spectrometry was conducted on the neat precursor powders, triphenylbismuth,  $\text{Bi}(\text{Ph})_3$ , and vanadium(III) acetylacetonate,  $\text{V}(\text{acac})_3$ , to investigate their decomposition at the temperatures used in our CVD reaction.  $\text{Bi}(\text{Ph})_3$  is expected to decompose to  $\text{Bi}_2\text{O}_3$ ,  $\text{V}(\text{acac})_3$  to  $\text{V}_2\text{O}_5$  and the 1 : 1 mixture to  $\text{BiVO}_4$  as these are the common fully oxidated forms. In Fig. 2a the TGA profiles show that  $\text{Bi}(\text{Ph})_3$  appears to lose mass primarily between 200–300 °C and then 400–500 °C. The  $\text{V}(\text{acac})_3$  loses mass during three temperature ranges between 150–200 °C, 200–250 °C, and 300–400 °C. A 1 : 1 mixture of  $\text{Bi}(\text{Ph})_3$  and  $\text{V}(\text{acac})_3$  also appears to lose mass in two major, albeit prolonged temperature ranges, between 150–250 °C and then 250–400 °C. The final residual mass of 22% for  $\text{V}(\text{acac})_3$  decomposition to  $\text{V}_2\text{O}_5$  was close to the expected value of 26%, while for  $\text{Bi}(\text{Ph})_3$  decomposition to  $\text{Bi}_2\text{O}_3$ ,





Fig. 1 Exemplar SEM images of (a) FTO substrate, (b) top view of  $\text{WO}_3$  NN, (c) top view of  $\text{WO}_3$  NN coated with 100 nm thick  $\text{BiVO}_4$ , (d) (top): side-on view of 100 nm thick  $\text{BiVO}_4$  on FTO, (bottom): top-down view of  $\text{BiVO}_4$ , (e) side-on view of 4000 nm long  $\text{WO}_3$  NN on FTO and (f) side-on view of 100 nm thick  $\text{BiVO}_4$  coated on 4000 nm long  $\text{WO}_3$  NN on FTO.

the 30% final residual mass was less than the expected value of 53%, which may be caused by partial sublimation of  $\text{Bi}(\text{Ph})_3$ ,<sup>44</sup> although any Bi-containing species were too heavy to be measured in the TGA-MS. Importantly, the final residual mass for the decomposition of the 1:1 mixture to  $\text{BiVO}_4$  of 40% matches the expected value of 41%.

The MS of  $\text{Bi}(\text{Ph})_3$  as a function of temperature, shown in Fig. 2b, shows a distinct release of benzene attributed to the release of the phenyl ligand between 200 and 300 °C, which corresponds to the first mass loss seen in the TGA. There is a brief pause in mass change before a second mass loss at 400 °C, corresponding to the release of  $\text{CO}_2$  until 500 °C, which may be attributed to the combustion of stray phenyl remaining in the material. In Fig. 2c, the MS of  $\text{V}(\text{acac})_3$  shows an initial loss of  $\text{H}_2\text{O}$  up to 100 °C which is likely surface adsorbed water from storage of the material in air. There are then three distinct peaks at 150 °C, 250 °C and 400 °C where characteristic fragments of the acetylacetonate ( $m/z$  43), water and  $\text{CO}_2$  are released, matching the temperatures for mass losses in the TGA. The area of the MS peaks also corresponds with the relative mass losses. In Fig. 2d, MS of the 1:1 mixture of  $\text{Bi}(\text{Ph})_3$  and  $\text{V}(\text{acac})_3$  shows all expected peaks from the individual materials with lower resolution, suggesting that decay of the solid-state mixture is generally a combination of the constituent individual compounds, and not from other (mixed-metal) intermediates. The  $\text{V}(\text{acac})_3$  precursor loses mass, and the corresponding products are observed by mass spectroscopy at approximately 50 °C lower compared to the

$\text{Bi}(\text{Ph})_3$  precursor, indicating that  $\text{V}(\text{acac})_3$  has a lower activation energy for decomposition than  $\text{Bi}(\text{Ph})_3$ .<sup>45</sup>

The choice of precursors should have an influence on the reaction mechanism for the deposition of the ternary metal oxide. An alternative commonly studied vanadium precursor for CVD is vanadyl(iv) acetylacetonate,  $\text{VO}(\text{acac})_2$ .<sup>46</sup>  $\text{VO}(\text{acac})_2$  has been reported with TGA to fully decompose by about 300 °C,<sup>47</sup> approximately 100 °C lower than for the complete decomposition of  $\text{V}(\text{acac})_3$ . If  $\text{VO}(\text{acac})_2$  is used in AACVD with  $\text{Bi}(\text{Ph})_3$ , there may then be a wider range of temperatures in which the two precursors have differing levels of decomposition. Use of  $\text{VO}(\text{acac})_2$  with  $\text{Bi}(\text{Ph})_3$  should then be avoided when stoichiometric  $\text{BiVO}_4$  is desired. According to UV-vis studies shown in Fig. S2,†  $\text{V}(\text{acac})_3$  decomposes and oxidises into  $\text{VO}(\text{acac})_2$  under atmospheric conditions over time when dissolved in 3:1 acetone:methanol. The oxidation process occurs rapidly over the first few hours and is followed by further oxidation to generate primarily  $\text{V}(\text{v})$  species over the course of two days. Therefore, we postulate that conducting AACVD using solutions containing  $\text{V}(\text{acac})_3$  aged for even only a few hours, may also have the same effect of using the  $\text{VO}(\text{acac})_2$  precursor directly, and, therefore, recommend the immediate use of  $\text{V}(\text{acac})_3$  stored under inert gases upon dissolution in the 3:1 acetone:methanol solution for CVD synthesis (where herein, depositions were conducted within ~15 min of dissolution).

Flat  $\text{BiVO}_4$  films prepared on FTO-coated glass at 400 °C show the XRD patterns for stoichiometric  $\text{BiVO}_4$  (Fig. 3). The as-





Fig. 2 TGA-mass spectrometry (MS) of the precursors used in the AACVD synthesis of  $\text{BiVO}_4$  (a) weight loss % as a function of temperature, and mass spectrometry of volatile materials for (b)  $\text{Bi}(\text{Ph})_3$ , (c)  $\text{V}(\text{acac})_3$ , and (d) 1 : 1 mixture of  $\text{Bi}(\text{Ph})_3$  and  $\text{V}(\text{acac})_3$ .



Fig. 3 XRD patterns for  $\text{BiVO}_4$  films grown on FTO-coated glass by AACVD before annealing (as deposited) and after annealing at 500 °C for 2 hours in air. Data is plot alongside PDF card references patterns for  $\text{SnO}_2$  (i.e. the FTO substrate),  $\text{BiVO}_4$ ,  $\text{Bi}_2\text{VO}_5$ ,  $\text{Bi}_2\text{O}_3$  and  $\text{V}_2\text{O}_5$ .

deposited sample shows the (002) (101) (011) (112) (004) (200) (020) (211) (015) (204) (024) (220) (116) (017) & (132) peaks corresponding to polycrystalline  $\text{BiVO}_4$  (monoclinic  $I112/b^{15}$   $a = 5.1907 \text{ \AA}$ ,  $b = 5.0912 \text{ \AA}$ ,  $c = 11.6941 \text{ \AA}$ ;  $\alpha = \beta = 90^\circ$ ,  $\gamma = 90.360^\circ$ ; PDF no. 01-090-8670) along with the (110) (101) (200) (211) (220) (310) & (301) diffraction peaks for the FTO substrate (tetragonal

$P4_2/mnm$  (136);  $a = b = 4.7380 \text{ \AA}$ ,  $c = 3.1865 \text{ \AA}$ ;  $\alpha = \beta = \gamma = 90^\circ$ ; PDF no. 01-071-0652). The effect of annealing the  $\text{BiVO}_4$  serves to eliminate the peak corresponding to the (101) crystalline plane, leaving only the (011) peak in the region near  $19^\circ$ . Peaks corresponding to  $\text{Bi}_2\text{VO}_5$  (PDF no. 01-086-1181),  $\text{Bi}_2\text{O}_3$  (PDF no. 01-080-9185) and  $\text{V}_2\text{O}_5$  (PDF no. 01-090-7484) are not evident



before or after annealing, indicating that the materials are deposited in a stoichiometric ratio and do not segregate into phases of the binary metal oxides.

Next, flat  $\text{BiVO}_4$  films were grown by CVD on FTO-coated glass for reactor temperatures between 250 and 450 °C. In these experiments the vanadium precursor was aged for one month in the solid state and therefore a minute amount of  $\text{Bi}_2\text{VO}_5$  was expected. Fig. S3† shows the XRD patterns for these films before and after annealing at 500 °C in air for two hours. For relatively low temperatures, at 250 °C neither precursor has begun to significantly decompose, so both species deposit on the substrate as amorphous solid solutions and the final film after annealing reflects the starting precursor stoichiometry. At relatively high deposition temperatures, 400 °C and 450 °C, both precursors rapidly decompose and crystallise together as-deposited, resulting in annealed films that also reflect the starting precursor stoichiometry. For moderate deposition temperatures at 300 °C and 350 °C, the  $\text{V}(\text{acac})_3$  decomposes to a greater extent compared to the  $\text{Bi}(\text{Ph})_3$ . Under these conditions, the lighter  $\text{V}(\text{acac})_3$  derivatives may be re-evaporated into the passing aerosol stream, increasing the relative amount of Bi in the film, with an additional  $\text{Bi}_2\text{VO}_5$  phase identified, evidenced by the relatively large and broad peak corresponding to the  $\text{Bi}_2\text{VO}_5$  (002) plane present after annealing.

These results suggest that differences in activation energy between the bismuth and vanadium metal-organic precursors allows for the control of  $\text{BiVO}_4$  stoichiometry with changing deposition temperature, with an optimal deposition temperature of 400 °C for fabricating  $\text{BiVO}_4$  for no observable sub-stoichiometric phases.

## 2.3 Chemical analysis of the $\text{WO}_3$ and $\text{BiVO}_4$ photoanodes

### 2.3.1 X-ray diffraction (XRD) and Raman spectroscopy.

Fig. 4a shows XRD patterns for representative samples of nanostructured  $\text{WO}_3$ ,  $\text{BiVO}_4$ , and  $\text{BiVO}_4$ -coated  $\text{WO}_3$ , grown on FTO-coated glass, with their characteristic Miller indices

labelled.<sup>48,49</sup> The nanostructured  $\text{WO}_3$  is preferentially orientated in the (002) plane and a single peak near 23° dominates, corresponding to monoclinic  $\text{WO}_3$  ( $P12_1/n1$ ;<sup>14</sup>  $a = 7.3271$  Å,  $b = 7.5644$  Å,  $c = 7.7274$  Å;  $\alpha = \gamma = 90^\circ$ ,  $\beta = 90.488^\circ$ ).<sup>34</sup> Peaks associated with the FTO substrate are indicated with asterisks (\*). The  $\text{BiVO}_4$ -coated  $\text{WO}_3$  samples have XRD peaks corresponding to both the polycrystalline monoclinic  $\text{BiVO}_4$  (ref. 50 and 51) and  $\text{WO}_3$  sample patterns. The peaks associated with nanostructured  $\text{WO}_3$  are preserved, even after the deposition and annealing of  $\text{BiVO}_4$ , indicating the formation of a sharp heterojunction between the two materials.

The Raman spectra shown in Fig. 4b show characteristic peaks matching literature spectra of  $\text{WO}_3$  (ref. 52 and 53) and  $\text{BiVO}_4$ , with the peak at 828  $\text{cm}^{-1}$  corresponding to the  $A_g$  symmetric vibrations of V–O bonds, the peaks at 366 and 327  $\text{cm}^{-1}$  corresponding to the  $B_g$  asymmetric and  $A_g$  symmetric modes of  $\text{VO}_4^{3-}$  respectively<sup>54</sup> and the peak at 211  $\text{cm}^{-1}$  being an external mode.<sup>55,56</sup> For the heterojunction spectrum, the widened peak seen at 827  $\text{cm}^{-1}$  is likely due to the combination of the  $A_g$  peak at 807  $\text{cm}^{-1}$  for  $\text{WO}_3$  and the  $A_g$  peak at 828  $\text{cm}^{-1}$  for  $\text{BiVO}_4$ .<sup>57</sup> The superimposed peaks of the  $\text{BiVO}_4$ -coated  $\text{WO}_3$ , therefore, suggest that distinct phases of  $\text{BiVO}_4$  and  $\text{WO}_3$  form in the heterostructure, and that a distinct interface is formed.

**2.3.2 X-ray photoelectron spectroscopy (XPS).** Exemplar flat samples of approximately 200 nm thick  $\text{WO}_3$ ,  $\text{BiVO}_4$ , and  $\text{BiVO}_4$ -coated  $\text{WO}_3$  on FTO-coated glass were measured by XPS to obtain information about their work function and stoichiometry. Average work function values were measured to be 4.3 and 4.5 eV below vacuum for  $\text{WO}_3$  and  $\text{BiVO}_4$  respectively, detailed in Table S1.† These values both shift to 4.8 eV upon surface cleaning with an argon ion-beam etch (evidenced by removal of the adventitious C 1s peak). The heterojunction  $\text{BiVO}_4$ -coated  $\text{WO}_3$  film has a similar work function of 4.5 eV before and 4.6 eV after etching.

Peak fitting of high-resolution XPS spectra confirm near stoichiometric values for  $\text{WO}_3$  and  $\text{BiVO}_4$ . Atomic% values of 25% for  $\text{W}^{6+}$ , 2% for  $\text{W}^{5+}$ , and 73% for  $\text{O}^{2-}$  were observed and is

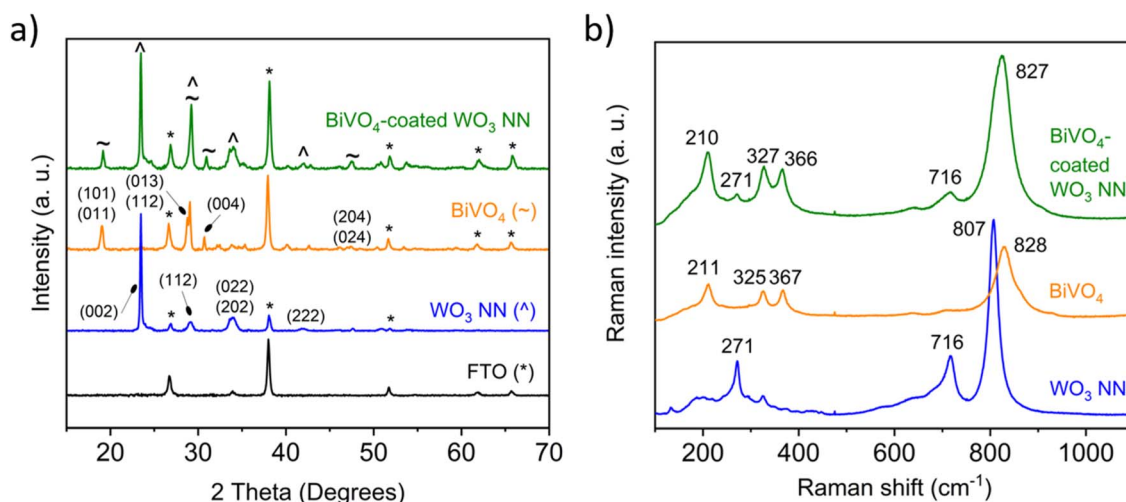


Fig. 4 (a) XRD patterns and (b) Raman spectra for 1000 nm long  $\text{WO}_3$  nanoneedles,  $\text{BiVO}_4$  and 50 nm thick  $\text{BiVO}_4$  coated on  $\text{WO}_3$  nanoneedles corresponding to monoclinic  $\text{WO}_3$  (ref. 34, 48 and 49) and monoclinic  $\text{BiVO}_4$ .<sup>50,51</sup>



commensurate with the expected stoichiometry of  $\text{WO}_3$  with approximately 2% oxygen vacancies. 14%  $\text{Bi}^{3+}$ , 12%  $\text{V}^{5+}$ , 6%  $\text{V}^{4+}$ , 1%  $\text{V}^{3+}$ , and 67%  $\text{O}^{2-}$  were the at% values observed for  $\text{BiVO}_4$ . The proportion of oxygen matches the expected stoichiometry, while the total amount of vanadium is similar to the bismuth. The mixture of vanadium reduced states may be induced by X-ray reduction during the XPS measurement. Survey scans and high-resolution peak fitting with elemental quantification are shown in Fig. S4 for  $\text{WO}_3$  and S5 for  $\text{BiVO}_4$ .† The peak fit parameters are also detailed in Tables S2 and S3† for  $\text{WO}_3$  and  $\text{BiVO}_4$  respectively.

## 2.4 Optical characterisation of the $\text{WO}_3$ and $\text{BiVO}_4$ photoanodes

Fig. 5a compares the absorbance spectra calculated from measured transmittance and total reflectance spectra (Fig. S6a and S6b†) of representative photoanode films of 2000 nm thick  $\text{WO}_3$  nanoneedles (NN) and 100 nm of  $\text{BiVO}_4$  conformally coated on 2000 nm thick  $\text{WO}_3$  NN on FTO-coated glass. As each layer is added, the absorption onset of the samples shifts from 350 nm for FTO-coated glass to 450 nm for  $\text{WO}_3$ -coated FTO, and finally to 510 nm for  $\text{BiVO}_4$ -coated  $\text{WO}_3$  on FTO. These values are consistent with the expected bandgaps for  $\text{SnO}_2$ ,  $\text{WO}_3$  and  $\text{BiVO}_4$  of 3.6,<sup>58</sup> 2.8 and 2.4 eV,<sup>11</sup> respectively. The overall optical properties of the layered materials are dominated by the absorbance of the constituent material with the smallest bandgap energy. For a more precise determination of the bandgap, a less scattering exemplar film was used, which consisted of a 400 nm thick  $\text{BiVO}_4$  layer coated onto a 100 nm thick flat (not nanostructured)  $\text{WO}_3$  underlayer. Flat  $\text{WO}_3$  is fabricated with a similar CVD procedure as for nanostructured  $\text{WO}_3$  using a lower substrate temperature.<sup>34</sup> The measured transmittance and total reflectance spectra of this film was used to produce a Tauc plot, shown in Fig. 5b, which revealed a 2.5 eV indirect transition and 2.6 eV direct transition for the  $\text{BiVO}_4$  layer. The transmittance and reflectance spectra of the flat films

are compared to the nanostructured films in Fig. S6a and S6b† showing the  $\text{WO}_3$  NN are less transmitting and more reflecting than flat  $\text{WO}_3$ , but samples of  $\text{BiVO}_4$  coated on flat and NN  $\text{WO}_3$  have similar properties. Fig. S7a and S7b† show Tauc plots for  $\text{WO}_3$  and  $\text{BiVO}_4$  grown directly on FTO, indicating indirect bandgaps of approximately 2.8 eV and 2.5 eV, respectively.

**2.4.1 Analysis of light attenuation through the photoanode layers.** Fig. 6 shows calculated light absorption through exemplar planar and nanostructured heterojunction films, modelled using data from UV-visible spectroscopy of films with known layer thicknesses. Optical losses, due to the reflection of light, are accounted for at each interface. For this analysis, the level of reflection (both specular and diffuse) that may occur at each interface are considered, with the nanostructured samples showing a higher degree of scattering (which can be seen with higher reflection losses between each interface in Fig. 6). The results illustrate how nanostructured samples can better harvest light at the band edge of the material compared with the flat heterojunction. First-order reflection at the interfaces of each layer are considered as losses, which is a simplification, but a conservative assumption at that. Also, light scattering would be expected for realistic nanostructured samples, but this effect would further increase absorption due to the additional chances for absorption and so the key takeaways are reinforced.

The optical behaviour of a planar  $\text{WO}_3/\text{BiVO}_4$  heterojunction system are shown in Fig. 6a and b, for back and front illumination, respectively. For such a system to be functional for water splitting, the planar layers cannot be too thick, or else both hole diffusion to the  $\text{BiVO}_4$  surface to drive water oxidation reactions and electron diffusion out of  $\text{BiVO}_4$  into  $\text{WO}_3$  would be inhibited. Thus, herein, we modelled the case for a 100 nm thick  $\text{WO}_3$  layer and a 400 nm thick  $\text{BiVO}_4$  layer. Under front illumination (Fig. 6a), UV light is effectively harvested by the  $\text{BiVO}_4$  layer, with ~80% of 250 nm and ~70% of 325 nm absorbed. Blue light is also strongly absorbed, with only ~20% of 400 nm and ~40% of 475 nm light remaining. Much of this light is then absorbed by the  $\text{WO}_3$  layer. Under back illumination (Fig. 6b), UV light of



Fig. 5 (a) UV-vis absorbance for 2000 nm thick  $\text{WO}_3$  NN and 100 nm  $\text{BiVO}_4$ -coated NN  $\text{WO}_3$  compared to FTO-coated glass and (b) Tauc plots derived from measurements of transmittance and total reflectance of 400 nm planar  $\text{BiVO}_4$  on 100 nm planar  $\text{WO}_3$  on FTO-coated glass.





Fig. 6 Calculated optical propagation of light through example heterojunction structures. Planar FTO/ $\text{WO}_3$ / $\text{BiVO}_4$  heterojunctions, with each respective layer being 320, 100 and 400 nm thick, for the case of (a) front illumination and (b) back illumination, and nanostructured FTO/ $\text{WO}_3$ / $\text{BiVO}_4$  heterojunctions with the FTO layer being 320 nm thick, coated with  $\text{WO}_3$  NN that are 100 nm wide and 2000 nm long, that are conformally coated with a 100 nm layer of  $\text{BiVO}_4$ , for the case of (c) front illumination and (d) back illumination. Pastel shading represents the layers of the heterojunction light is passing through; colourless = FTO, blue =  $\text{WO}_3$ , green =  $\text{BiVO}_4$ . Calculations were carried out for 250, 325, 400 and 475 nm light.

250 nm is almost all absorbed by the FTO layer, and therefore cannot be harvested by the heterojunction. Similarly,  $\sim 60\%$  of UV light of 325 nm is absorbed by the FTO layer. This is then strongly absorbed by the proceeding  $\text{WO}_3$  layer. For the cases of 400 and 475 nm light, these are not significantly attenuated by the FTO layer. About 40% of 400 nm light and 20% of 475 nm light is absorbed by the  $\text{WO}_3$  layer, with only  $\sim 20\%$  of the remaining 400 and 475 nm light absorbed upon reaching the  $\text{BiVO}_4$  layer. Overall, back illumination of the planar heterojunction shows that UV light (*i.e.* 250 and 325 nm) cannot be harvested effectively due to parasitic absorption by the FTO layer, and that light near the band edge of  $\text{BiVO}_4$  (*i.e.* 475 nm) is not effectively harvested either.

For the case of a nanostructured heterojunction  $\text{WO}_3/\text{BiVO}_4$  system, the nanostructured  $\text{WO}_3$  layer can decouple the limited electron and hole diffusion of the conformally coated  $\text{BiVO}_4$ . Moreover, given the excellent electron transport found in  $\text{WO}_3$ , one can use a microns-thick nanostructured layer. Thus, herein,

we modelled the case for a nanostructured  $\text{WO}_3$  layer with rods 100 nm wide and 2000 nm long that are coated with a 100 nm conformal  $\text{BiVO}_4$  layer, like what we have produced experimentally herein (Fig. 1). A cross-section is modelled that transects the middle of the nanorod, where light encounters the  $\text{WO}_3$  layer one-third of the time and the  $\text{BiVO}_4$  layer two-thirds of the time. For the case of front illumination (Fig. 6c), all light from 250 to 475 nm is harvested within the  $\text{WO}_3/\text{BiVO}_4$  nanostructure, which results in optimal charge carrier production. Under back illumination (Fig. 6d), significant absorption within the FTO layer is seen for 250 nm and 325 nm light, just as for the planar heterojunction (Fig. 6c). Different behaviour is, however, seen for longer wavelengths, with all 400 and 475 nm light absorbed by the nanostructured architecture because of the increased length of the absorber. The  $\text{BiVO}_4$  layer in the nanostructured architecture is more capable of harvesting light, particularly wavelengths at the band edge of the material where a more significant portion of the solar spectrum resides. The



micron-scale distance that light must travel through the  $\text{BiVO}_4$  in the nanostructured heterojunction results in all the light being absorbed, whereas residual light is transmitted through the flat heterojunctions. Under back illumination, exciton electron-hole pairs are formed much closer to the FTO electron collector than for photoanodes under front illumination.

## 2.5 Photoelectrochemical (PEC) experiments

**2.5.1 Current voltage ( $J$ - $V$ ) investigation.** Fig. 7 compares representative  $J$ - $V$  curves of PEC modules using  $\text{WO}_3$  NN or  $\text{BiVO}_4$  as the photoanode with the  $J$ - $V$  curve of the  $\text{BiVO}_4$ -coated  $\text{WO}_3$  heterojunction photoanode under front and back illumination. The  $\text{WO}_3$  NN investigated are 1000 nm thick, and the  $\text{BiVO}_4$  is 200 nm thick when deposited on FTO and 50 nm thick when coated on  $\text{WO}_3$ . The heterojunction photocurrent density is significantly increased compared to photoanodes made with a single constituent material, which evidences the effect of improved charge separation across the heterojunction interface. The photocurrents of 0.35 and 0.45  $\text{mA cm}^{-2}$  for the heterojunction at an applied potential of 1.23 V vs. RHE under front and back-illumination respectively are significantly improved from the 0.16 and 0.12  $\text{mA cm}^{-2}$  for  $\text{BiVO}_4$  under front and back illumination and 0.05  $\text{mA cm}^{-2}$  for  $\text{WO}_3$  under front illumination. The low photocurrent for the  $\text{WO}_3$  photoanode is attributed to its large bandgap and limited visible light absorption. Furthermore, the white light of the 75 W xenon lamp used, although able to provide overall illumination matching 1 sun intensity, has discrepancies in its intensity of light with shorter wavelengths, shown in Fig. S8,† compared to the AM1.5G solar spectrum. This limitation reduces the apparent photocurrent measured using the white light, but there are significant cost benefits to using a 75 W xenon lamp. A spectrally matching

solar simulator requires a 500 W or higher lamp coupled to air mass filters with a lifetime of only 1000 hours compared to 3000 hours for 75 W lamps.<sup>59</sup> Incident photon conversion efficiency measurements using monochromated light fully mitigate this limitation and allow for direct comparison with the AM1.5G solar spectrum.

Current density losses along the length of the nanostructures and mass transport losses arising from the increased distance that reactants and products travel between the electrode surface and electrolyte bulk may limit the ultimate photocurrents. It was previously shown by Kafizas *et al.*, however, that nanostructured  $\text{WO}_3$  had significantly increased photoanode performance compared to flat  $\text{WO}_3$ .<sup>34</sup> This result was attributed to the full utilisation of photon penetration depth that increases the light absorption through the length of the needles.<sup>34</sup> The increase in surface area likely also contributes to mitigating current density and mass transport losses in highly crystalline, annealed  $\text{WO}_3$  nanostructures where oxygen vacancy defects are minimized to improve electron transport.<sup>60</sup>

**2.5.2 Incident photon conversion efficiency (IPCE).** The IPCE profiles of 66 distinct samples (triplicates of 22 recipes) with differing  $\text{WO}_3$  and  $\text{BiVO}_4$  layer thickness, as described in Table 1, were measured at 1.23 V vs. RHE using monochromatic light from 250 to 550 nm. IPCE profiles from 7 of these samples are plotted in Fig. 8 to show trends in performance. Fig. 8a shows the IPCE profiles for various thickness of  $\text{BiVO}_4$  coatings on 1000 nm long  $\text{WO}_3$  NN. These samples of  $\text{WO}_3$  are best coupled with a 25 nm thick  $\text{BiVO}_4$  coating for optimal IPCE under both front and back illumination. In general, back illumination outperformed front illumination at longer wavelengths. At short wavelengths, back illumination is hindered by absorption from the FTO-coated glass of the photoanode, although the solar spectrum will contain limited photons with wavelengths shorter than 300 nm.<sup>61</sup>

Fig. 8b compares the IPCE profiles for samples with an aspect ratio of NN to  $\text{BiVO}_4$  thickness of 40 : 1. The thinnest samples with 500 nm long  $\text{WO}_3$  NN show the least IPCE under back illumination, the samples with 1000 nm long  $\text{WO}_3$  NN showed moderate efficiency for both front and back illumination, and the samples with 2000 nm long  $\text{WO}_3$  NN demonstrated the highest efficiency under back illumination. The difference in the photocurrents of the front and back-illuminated photoanodes for the thickest photoanode is likely due to more facile extraction of excited majority carrier electrons away into the circuit when the excitons are formed close to the substrate compared to when they are formed near the photoanode surface under front illumination. The optimal  $\text{BiVO}_4$ -coated  $\text{WO}_3$  nanoneedle photoanodes show excellent visible light photoactivity with up to approximately 50% IPCE for visible light with wavelengths up to 450 nm.

**2.5.3 Photoanode water splitting stability.** The stability of a representative nanostructured  $\text{WO}_3/\text{BiVO}_4$  photoanode was tested under illumination and 1.23 V vs. RHE applied potential. Fig. 9a and b show chronoamperometry measurements over four hours for front and back illumination, respectively. A chopped light measurement was taken (light on & off, in 10 second intervals) before and after the stability measurements



Fig. 7  $J$ - $V$  curves for 1000 nm thick  $\text{WO}_3$  NN (pH 1.1, 0.1 M  $\text{H}_2\text{SO}_4$  (aq.)), 200 nm thick  $\text{BiVO}_4$  and 50 nm thick  $\text{BiVO}_4$ -coated 1000 nm thick  $\text{WO}_3$  NN (pH 7, 0.1 M  $\text{K}_2\text{HPO}_4/\text{KH}_2\text{PO}_4$  (aq.)) on TEC15 FTO-coated glass. Scan rate: 10  $\text{mV s}^{-1}$ , illuminated with a 75 W Xe lamp attenuated with a neutral density filter at approximately 1 sun intensity. Solid lines represent front illumination, and dashed lines represent back illumination.





Fig. 8 Exemplar IPCE profiles for  $\text{BiVO}_4$ -coated  $\text{WO}_3$  on FTO, measured at pH 7 in 0.1 M  $\text{KH}_2\text{PO}_4/\text{K}_2\text{HPO}_4$  (aq.) buffer electrolyte under front and back illumination (dashed lines), with 95% confidence intervals for triplicate measurements (a) varying  $\text{BiVO}_4$  on 1000 nm long  $\text{WO}_3$  nanoneedles, and (b) constant ratio of varying  $\text{BiVO}_4$  and  $\text{WO}_3$  nanoneedle thicknesses.

and are shown on magnified timescales. Both measurements show stable photocurrents over four hours, which is commensurate with other studies of long-term  $\text{BiVO}_4$  (ref. 60) and  $\text{BiVO}_4$ -based heterojunction<sup>62</sup> photoelectrocatalysis, but further tests lasting hundreds of hours will be needed as evidence of commercially-applicable photocurrent stability. SEM imaging of a heterojunction sample after several hours of chronoamperometric and cyclic voltametric testing are depicted in Fig. S9† and show that the length of the nanoneedles remains stable. The needles are still coated in  $\text{BiVO}_4$ , although there appears to be changes in shape of the surface of the material that may be a result of partial dissolution and rearrangement. The photocurrents recorded are lower than the solar predicted photocurrents discussed in the next section because of the mismatch between the spectrum of the xenon lamp and the solar spectrum, discussed earlier.

**2.5.4 Solar predicted photocurrent (SPP) for heterojunction devices.** The expected solar predicted photocurrent (SPP) of photoanodes illuminated by the AM1.5G solar spectrum is calculated by fitting a model to the IPCE curves to interpolate between the measured points. The conversion efficiency at each wavelength is then multiplied by the solar photon flux spectrum and integrated over all wavelengths. Fig. 10a and b show representative calculations of SPP for the optimal average IPCE profiles of 1000 nm thick  $\text{WO}_3$  NN coated with 25 nm of  $\text{BiVO}_4$  under front illumination and the 2000 nm thick  $\text{WO}_3$  NN coated with 50 nm of  $\text{BiVO}_4$  under back illumination, respectively. Most harvested photons have wavelengths between 400 and 450 nm due to the combination of high IPCE and high solar photon flux in this region. Fig. 10c and d show heatmaps of SPP created from the IPCE results of the 22 unique samples produced herein (Table 1) with varying  $\text{WO}_3$  nanoneedle and



Fig. 9 Chronoamperometry stability measurements of a representative 500 nm long  $\text{WO}_3/50$  nm thick  $\text{BiVO}_4$  heterojunction photoanode illuminated with a 75 W Xe lamp attenuated with a neutral density filter at approximately 1 sun intensity under (a) front and (b) back illumination. Electrolyte: 0.1 M, pH 7  $\text{KH}_2\text{PO}_4/\text{K}_2\text{HPO}_4$  (aq.), 1.23 V vs. RHE. X-axis scale varies as indicated.





Fig. 10 Calculations of solar predicted photocurrent (SPP) from the IPCE measured at 1.23 V vs. RHE for the nanostructured  $\text{WO}_3/\text{BiVO}_4$  heterojunction samples showing the highest average performance under (a) front illumination (1000 nm thick  $\text{WO}_3$  NN coated with 25 nm of  $\text{BiVO}_4$ ) and (b) back illumination (2000 nm thick  $\text{WO}_3$  NN coated with 50 nm of  $\text{BiVO}_4$ ). Heat maps of the SPP for varying thicknesses of  $\text{WO}_3$  nanoneedles and  $\text{BiVO}_4$  in the heterojunction for the 22 unique samples examined for (c) front illumination and (d) back illumination.

$\text{BiVO}_4$  thickness for front and back illumination, respectively. The presence of  $\text{BiVO}_4$  is key to increasing the absorption of visible light of the  $\text{WO}_3$ , and the heterojunction improves the SPP in all cases for moderate thicknesses of  $\text{BiVO}_4$ . The average SPP for the front-illuminated devices peaks at  $1.9 \text{ mA cm}^{-2}$  for the samples with 1000 nm thick  $\text{WO}_3$  nanoneedles and a 25 nm coating of  $\text{BiVO}_4$ , while the average SPP for the back-illuminated devices peaks at  $2.6 \text{ mA cm}^{-2}$  for the samples with 2000 nm thick  $\text{WO}_3$  nanoneedles and a 50 nm coating of  $\text{BiVO}_4$ . If the applied potential (1.23 V vs. RHE) is provided from an additional solar-powered source placed optically in tandem (e.g. a PV), these values would equate to 2.3% and 3.2% solar-to-hydrogen (STH) conversion efficiency, respectively.

## 2.6 Model of a hypothetical PV-coupled PEC water splitting device

A hypothetical PV-coupled PEC water splitting (PV-PEC) device is arranged with a photoanode, metal cathode mesh, and silicon PV system optically in tandem as shown in Fig. 11a. The photoanode is illuminated from the backside to avoid being shaded by other device components such as the Pt cathode or electrolyte. The orientation of the cathode should be placed parallel to the photoanode for optimal mass transport of ions in solution

and to reduce pH gradients in electrochemical set-ups.<sup>30</sup> In our hypothetical device, the dual c-Si PV collects the transmitted light after passing through the whole PEC module.

In Fig. 11b, PV-PEC system  $J$ - $V$  curves are shown for three cases of  $\text{BiVO}_4$ -coated  $\text{WO}_3$  placed in front of dual c-Si PV modules as in Fig. 11a. The  $J$ - $V$  curves for the PV module are simulated in MATLAB using eqn (1) considering the light transmitted through the PEC photoanode and other optical losses. Transmittance spectra for all the PEC photoanodes were measured and plotted in Fig. S10.†  $J_{\text{sc}}$  is the calculated short-circuit current based on the solar spectrum and a conservative external quantum efficiency of 90%.  $J_0$  is the calculated exchange current,  $R_s$  is the series resistance,  $0.001 \text{ k}\Omega \text{ cm}^2$ ,<sup>63</sup> and  $R_{\text{sh}}$  is the shunt resistance,  $10 \text{ k}\Omega \text{ cm}^2$ ,<sup>64</sup> taken for a typical c-Si PV cell.  $e$  is the elemental charge,  $n$  is the ideality factor,  $k$  is Boltzmann's constant, and  $T$  is the temperature, taken as 297 K.

$$J = J_{\text{sc}} - J_0 \exp\left[\frac{e(V + JR_s)}{nkT}\right] - \frac{V + JR_s}{R_{\text{sh}}} \quad (1)$$

The operating points of the three tested PV-PEC systems in Fig. 11b are highlighted at the intersections between the three





Fig. 11 (a) Schematic of the hypothetical PV-PEC device with a dual c-Si PV electrically in series and optically in tandem with a back-illuminated PEC photoanode, (b)  $J$ - $V$  curves for samples as indicated under back illumination as solid lines, and simulated  $J$ - $V$  curves of corresponding dual c-Si PV modules behind the PEC module as dashed lines. Simulations and measured curves are calibrated to AM1.5G 1 sun illumination.

sets of PV and PEC  $J$ - $V$  curves. The PV-PEC systems utilising a 2000 nm long  $\text{WO}_3$  NN photoanode coated with 100 nm thick  $\text{BiVO}_4$  and a 1000 nm long  $\text{WO}_3$  NN photoanode coated with 50 nm thick  $\text{BiVO}_4$  are simulated to have PV-PEC system operating currents of  $0.5 \text{ mA cm}^{-2}$  and  $0.8 \text{ mA cm}^{-2}$  respectively. The operating current for the simulated PV-PEC system with the 2000 nm long  $\text{WO}_3$  NN photoanode coated with 50 nm thick  $\text{BiVO}_4$  was an optimal value of  $2.8 \text{ mA cm}^{-2}$ , which equates to an STH efficiency of 3.4%. This simulation shows the importance of increasing photocurrent from the PEC component and reflects the trends in system performance shown in Fig. 10 because the PV module in each case is providing an excess of photocurrent.

## 2.7 Comparison of similar unassisted PV-PEC systems in the literature

A wide range of unassisted PEC-based systems have been explored in the literature, including fully PEC<sup>65,66</sup> and PV-PEC tandem devices. Herein, we focus exclusively on literature

examples where  $\text{WO}_3$  and/or  $\text{BiVO}_4$  were applied as a photoanode in conjunction with a PV to achieve unassisted water splitting. Their performances are summarised in Table 2.

Kafizas *et al.* produced nanoneedle-structured  $\text{WO}_3$  photoanodes using an analogous AACVD method to that applied in this work.<sup>34</sup> Their highest performing material was composed of a 300 nm flat  $\text{WO}_3$  seed layer with a  $5 \mu\text{m}$  top layer of  $\text{WO}_3$  nanoneedles. Under back irradiation, this material showed an SPP of  $1.24 \text{ mA cm}^{-2}$  at  $1.23 \text{ V vs. RHE}$ , and when coupled in tandem with a photovoltaic device containing a methylammonium lead iodide perovskite (MAPI), an STH of 0.75% for unassisted water splitting was predicted. Sivula *et al.* produced  $2.5 \mu\text{m}$  thick mesoporous  $\text{WO}_3$  photoanodes through a sol-gel process that showed  $2.4 \text{ mA cm}^{-2}$  at  $1.23 \text{ V vs. RHE}$  and 1 sun irradiance.<sup>67</sup> When coupled to a high open-circuit voltage cobalt-based dye-sensitized solar cell (DSC), it showed an unassisted STH of 3.1%.<sup>67</sup>

Kamat *et al.* demonstrated a tandem  $\text{BiVO}_4$  photoanode coupled with a MAPI PV that achieved STH efficiencies of

Table 2 Comparison of PV-PEC water splitting device performances from the literature focusing on metal oxide photoanode-based systems

PEC - PV	PEC synthesis	Biased $J^a$ ( $\text{mA cm}^{-2}$ )	SPP ( $\text{mA cm}^{-2}$ )	Unassisted PV-PEC STH (%)	Ref.
$\text{WO}_3$ - MAPI	AACVD	n.a.	1.24	0.75	34
$\text{WO}_3$ - DSC	Sol-gel	2.4	2.23	3.1	67
$\text{BiVO}_4/\text{CoPi}$ - MAPI	MOD + PAE	2.2	n.a.	2.0	68
$\text{BiVO}_4/\text{Ni:FeOOH}$ - OPV	ED + PAE	1.9	n.a.	2.2	69
$\text{SiO}_x/\text{BiVO}_4/\text{Ni:FeOOH}$ - MAPI	RIE + MOD + ED	6.0	n.a.	6.2	70
$\text{WO}_3/\text{BiVO}_4/\text{CoPi}$ - GaAs/InGaAsP	GLAD + ED + ED	6.7	n.a.	8.1	19 and 68
$\text{TiO}_2/\text{WO}_3/\text{BiVO}_4/\text{Fe(Ni)OOH}$ - n-Si/ $\text{SiO}_2$	AACVD + spin coating	2.6	n.a.	0.31	27
W: $\text{BiVO}_4/\text{Co-Pi}$ - thin-film amorphous Si	Spray pyrolysis	4.0	n.a.	5.2	71
H, 1% Mo: $\text{BiVO}_4/\text{NiFeO}_x$ - crystalline silicon PV	Drop-casting & calcination	4.5	n.a.	3.0	72
$\text{WO}_3/\text{BiVO}_4$ - c-Si	AACVD + AACVD	n.a.	2.61	3.2	This work

<sup>a</sup> PEC only at  $1.23 \text{ V vs. RHE}$  and 1 sun illumination using solar simulated light; n.a. = not applicable.



2.0%.<sup>68</sup> Their BiVO<sub>4</sub> was produced using metal organic deposition (MOD) and was coated with a cobalt phosphate (CoPi) surface co-catalyst using photo-assisted electrochemical (PAE) deposition.<sup>68</sup> It resulted in a photocurrent density of 2.2 mA cm<sup>-2</sup> at 1.23 V vs. RHE and 1 sun irradiance.<sup>68</sup> Andrew *et al.* produced 700 nm thick mesoporous BiVO<sub>4</sub> photoanodes using electrochemical deposition (ED) that were coated with a nickel : iron oxyhydroxide (Ni : FeOOH) co-catalyst using PAE deposition.<sup>69</sup> Their photoanodes showed a photocurrent density of 1.9 mA cm<sup>-2</sup> at 1.23 V vs. RHE and 1 sun irradiance, and when coupled with a non-fullerene acceptor organic photovoltaic (OPV) showed an unassisted STH of 2.2%.<sup>69</sup> Using SiO<sub>x</sub> nanocones, produced using a reactive ion etching process (RIE), Qiu *et al.* grew a conformal coating of Mo-doped BiVO<sub>4</sub> on top using a MOD followed by a Ni : FeOOH surface co-catalyst using PAE deposition.<sup>70</sup> Their photoanodes showed photocurrent density of 6.0 mA cm<sup>-2</sup> at 1.23 V vs. RHE and 1 sun irradiance, and when coupled with a MAPI PV showed an unassisted STH of 6.2%.<sup>70</sup> Lastly, the current state-of-the-art example, produced by Pihosh *et al.*, is a nanostructured WO<sub>3</sub>/BiVO<sub>4</sub>/CoPi system.<sup>19</sup> 3 μm long WO<sub>3</sub> nanorods were made using glancing angle deposition (GLAD) and were coated with BiVO<sub>4</sub> and CoPi using ED methods.<sup>19</sup> Their photoanodes showed a photocurrent density of 6.72 mA cm<sup>-2</sup> at 1.23 V vs. RHE and 1 sun irradiance, and when coupled to a double-junction GaAs/InGaAsP PV showed an unassisted STH efficiency of 8.1%.<sup>19</sup>

Herein, we synthesised nanoneedle-structured WO<sub>3</sub> with a conformal coating of BiVO<sub>4</sub> using an AACVD method at ambient pressures (Fig. S1†), which simplifies the operation of and reduces the equipment and operating costs compared to many of the above-mentioned deposition techniques that require vacuum conditions. No surface co-catalyst as yet was applied in this work, which is often a pre-requisite for higher performance in this heterojunction system. Our best performing heterojunction was composed of 2000 nm long WO<sub>3</sub> nanoneedles coated with a 50 nm thick conformal BiVO<sub>4</sub> layer showing an SPP of 2.61 mA cm<sup>-2</sup> under back irradiation, and when coupled to a dual c-Si PV in tandem, our modelling predicted an STH of 3.2%. Overall, the performance we observe is comparable to other examples from the literature. Notably, the higher performing examples use surface co-catalysts to achieve more favourable onset potentials and photocurrent densities in their photoanode, which was not explored herein but will be the subject of future work. Also, these examples that achieved higher performance used synthetic techniques that are not readily scalable (*e.g.* RIE, GLAD, *etc.*), and are therefore unlikely to be used in the commercial mass-production of this technology. Broadly, many of the PVs applied in these studies are either not commercially available (*e.g.* DSC, MAPI and OPV) or not cost effective (GaAs/InGaAsP). As such, the focus of this work was to use a scalable synthetic technique such as CVD, which is currently used to produce FTO-coated glass and can therefore be applied in line to produce photoanodes, alongside a PV material that is commercially available and low cost (*i.e.* c-Si). Fig. S1† shows a photograph of our CVD reactor which can deposit samples up to 16 cm × 5 cm surface area. A further

publication currently in preparation will demonstrate the ability for our CVD method to produce arrays of photoanodes on a larger scale – increasing the size from the ~1 cm<sup>2</sup> to >50 cm<sup>2</sup> scale – and couple these with c-Si PV in tandem to demonstrate unassisted water splitting at a scale more commensurate to its future commercial application.

### 3. Conclusions

BiVO<sub>4</sub>-coated WO<sub>3</sub> nanostructured photoanodes for the water oxidation reaction were fabricated by aerosol-assisted chemical vapour deposition (AACVD) at atmospheric pressure, which is a considerable simplification and reduction in equipment costs compared to deposition under vacuum conditions. This work demonstrates the potential for AACVD to fabricate effective photoanodes for water splitting devices, despite not yet applying co-catalysts to our heterojunction system, which often results in higher performance. The mechanism of ternary BiVO<sub>4</sub> deposition by CVD was investigated by thermogravimetric analysis of the metal-organic precursors used. TGA provided evidence of a difference in activation energy for decomposition between the precursors. XRD evidence of sub-stoichiometric phases of BiVO<sub>4</sub> deposited at intermediate 300–350 °C temperatures allowed us to conclude that the stoichiometry of BiVO<sub>4</sub> depends on the deposition temperature, rather than solely on the ratio of precursors in the starting deposition solution. CVD deposition of WO<sub>3</sub>/BiVO<sub>4</sub> heterojunction photoanodes that showed photocurrents more than double compared to bare BiVO<sub>4</sub> and several times that of bare WO<sub>3</sub> photoanodes. The optimal solar predicted photocurrents of 1.9 mA cm<sup>-2</sup> under front illumination and 2.6 mA cm<sup>-2</sup> under back illumination for the samples tested represent promising STH conversion efficiencies of 2.3% and 3.2% respectively.

PV modules that can provide the 1.23 V vs. RHE to drive a PEC device include dual crystalline silicon cells connected electrically in series because they can absorb the red and near-infrared light, not utilised by the photoelectrode and are commercially available for a relatively low cost. We thus developed a model that simulates the performance of tandem PV-PEC devices, where our WO<sub>3</sub>/BiVO<sub>4</sub> heterojunction photoanodes were coupled to a dual c-Si PV in tandem, and a maximum STH performance of 3.2% was predicted. Further increases in the PEC photocurrent and in the photovoltage provided by the PV module would shift the operating current to higher values. A further publication currently in preparation will demonstrate the ability for our CVD method to produce arrays of photoanodes on a larger scale (>50 cm<sup>2</sup>) more commensurate to commercial application. There exists a need to examine larger scale, unassisted water splitting devices, so that techno-economic and life-cycle analyses can be more accurately conducted. Furthermore, additional steps may be implemented using AACVD, such as the incorporation of surface co-catalysts, to beneficially cathodically shift the onset potential and increase the plateau photocurrents to achieve higher overall STH efficiency.



## 4. Experimental section

### 4.1 Metal oxide fabrication by chemical vapour deposition

The metal-organic precursors tungsten hexacarbonyl (97%, Aldrich), bismuth triphenyl (98+%, Alfa Aesar), and vanadium(III) acetylacetonate (97%, Aldrich) were used as received. FTO-coated glass substrates ( $1.33 \times 2.5 \text{ cm}^2 \times 0.22 \text{ cm}$  thick) (TEC 15, Pilkington) were cleaned by successive sonication (VWR ultrasonic cleaner, 30 W, 45 kHz) in detergent with deionised water, deionised water, acetone, and isopropanol for 10 minutes each. The substrates were placed on a carbon block in a custom-built quartz tube reaction chamber and heated to the target deposition temperature. For  $\text{WO}_3$  deposition, varying volumes of 11.4 mM concentration precursor solution in 3 : 1 acetone and methanol was aerosolised by a humidifier (Liquifog®, Johnson Matthey, ~1.6 MHz operating frequency) and carried into the reaction chamber by a  $2 \text{ L min}^{-1}$  flow of inert  $\text{N}_2$  gas. The carbon block was heated with an internal cartridge heater to  $375 \text{ }^\circ\text{C}$  to grow nanoneedle films and to  $325 \text{ }^\circ\text{C}$  to grow flat  $\text{WO}_3$  films as shown previously by Kafizas *et al.*<sup>34</sup> Following complete transfer of precursor, the films were annealed in a  $500 \text{ }^\circ\text{C}$  furnace (Nabertherm Electric Muffle Furnace, L 9/11/B410) in air for 2 hours (temperature ramp rate of  $200 \text{ }^\circ\text{C}$  per hour), which leaves an optimal quantity of oxygen vacancies in the films.<sup>37</sup> Deposition of  $\text{BiVO}_4$  occurred similarly with varying volumes of 5 mM concentration precursor solution aerosolised and carried into the reaction chamber by a  $1 \text{ L min}^{-1}$  flow of compressed air. The carbon block was heated to  $400 \text{ }^\circ\text{C}$  during the deposition. Annealing of the  $\text{BiVO}_4$  was also done at  $500 \text{ }^\circ\text{C}$  for 2 hours in air, which crystallises the  $\text{BiVO}_4$  with an optimal grain size while limiting vanadium vacancies that form trap states for recombination<sup>73</sup> and reduces propensity to dissolve upon illumination in phosphate electrolyte solutions.<sup>74</sup> Heterojunction samples were fabricated by sequentially depositing  $\text{WO}_3$ , annealing at  $500 \text{ }^\circ\text{C}$  for 2 hours, and depositing  $\text{BiVO}_4$  before a second annealing stage while adjusting the volumes of precursor solution transferred.

### 4.2 Physical characterisation

Scanning electron microscopy (SEM) images were taken with a Zeiss Auriga microscope with a 5 kV acceleration voltage, Inlens detector, and 5 mm working distance. Side-on SEM images of sample cross sections were used to determine that the  $\text{WO}_3$  nanoneedles deposited at a rate of 500 nm per 10 mL of precursor,  $\text{BiVO}_4$  deposited on nanoneedles at a rate of 25 nm per 10 mL of precursor, and 100 nm per 10 mL of  $\text{BiVO}_4$  precursor on flat surfaces. Thermo-gravimetry analysis with mass spectrometry (TGA-MS) was tested with a Mettler Toledo TGA/DSC 1LF/UMX, HIDEN ANALYTICAL HPR-20 QIC Evol. Precursor powders stored in air with initial masses of approximately 5 mg were tested under air gas environment at constant heating rate of  $10 \text{ }^\circ\text{C}$  per minute. X-ray diffraction (XRD) patterns were measured with a Bruker D2 Phaser diffractometer with parallel beam optics equipped with a Lynx-Eye detector. X-rays were generated using a Cu source ( $V = 30 \text{ kV}$ ,  $I = 10 \text{ mA}$ ) through a 0.6 mm slit; with Cu  $K_{\alpha 1}$  ( $\lambda = 1.54056 \text{ \AA}$ ) and Cu  $K_{\alpha 2}$  radiation ( $\lambda$

$= 1.54439 \text{ \AA}$ ) emitted with an intensity ratio of 2 : 1. Patterns were collected between  $10^\circ \leq 2\theta \leq 70^\circ$  with a step size of  $0.0527^\circ$  and a speed of 1 second per step. Patterns were compared to references from the Physical Sciences Data-Science (PSDS) database. Raman spectra were obtained using a Horiba LabRAM Infinity spectrometer equipped with a helium-neon laser (633 nm, 8 mW) from 100 to  $1100 \text{ cm}^{-1}$ . X-ray photoelectron spectroscopy (XPS) between 0 and 1400 eV binding energy was measured with a Thermo Fisher K-Alpha+ automated system with Al  $K_{\alpha}$  X-ray source and ion beam etch sputterer. Transmittance and reflectance of solid films were measured by a Shimadzu UV-2600 UV-vis spectrometer with integrating sphere in the range of 190 to 1200 nm with 1 nm resolution. Solution phase UV-vis spectroscopy was carried out on a Shimadzu 2600i spectrometer.

### 4.3 Photoelectrochemical experiments

A three-electrode set-up in a cappuccino-type cell<sup>75,76</sup> was used in all experiments with a pH 7, 0.1 M aqueous potassium phosphate buffer electrolyte (potassium phosphate dibasic, ACS reagent  $\geq 98\%$ , Sigma-Aldrich & potassium phosphate monobasic, ACS reagent  $\geq 99\%$ , Sigma-Aldrich) made with  $18.2 \text{ M}\Omega \text{ cm}$  ultrapure water. Pt mesh and an Ag/AgCl (saturated KCl) electrode served as the counter and reference electrode respectively. Potentials *versus* the Ag/AgCl reference electrode were applied using a Metrohm Autolab PGSTAT 101 and converted to the reversible hydrogen electrode scale using the Nernst equation:  $V_{\text{RHE}} = V_{\text{Ag/AgCl}} + 0.0592 \times \text{pH} + V_{\text{Ag/AgCl}}^0$ , for  $V_{\text{Ag/AgCl}}^0 = 0.197 \text{ V vs. RHE}$ . Illumination was provided by a 75 W Xe lamp and monochromator (OBB-2001, Photon Technology International) and calibrated with a Thorlabs optical power meter with photodiode sensor (PM100D Power Energy Meter equipped with a S120VC sensor). The PEC performances are quantified by measuring the current-voltage ( $J$ - $V$ ) characteristic curves and the incident photon to current efficiency (IPCE) profiles.  $J$ - $V$  Curves are obtained by linear sweep voltammetry at  $10 \text{ mV s}^{-1}$  under white light illumination by approximately 1 sun intensity as determined by measuring the photocurrent with a Si photodiode. IPCE values are obtained by changing the wavelength of calibrated monochromatic light while measuring the photocurrent by chronoamperometry under applied potential of 1.23 V *vs.* RHE. The IPCE was calculated using the following equation:

$$\text{IPCE}(\%) = (I_{\text{ph}} \times 1239.8) / (P_{\text{mono}} \times \lambda) \times 100 \quad (2)$$

where  $I_{\text{ph}}$  is the photocurrent ( $\text{mA cm}^{-2}$ ), 1239.8 is the multiplication of Planck's constant with the speed of light ( $\text{eV nm}$ ),  $P_{\text{mono}}$  is the light power at a given wavelength ( $\text{mW cm}^{-2}$ ) and  $\lambda$  is the wavelength of the monochromated light (nm). The solar water splitting activity was calculated using IPCE measurements. The solar predicted photocurrent (SPP) was determined by multiplying the IPCE with the AM1.5 solar spectrum and integrating over all wavelengths to determine the total current.

$$\text{SPP}(\text{mA cm}^{-2}) = \int_{280 \text{ nm}}^{E_{\text{bg}}(\text{nm})} (\text{IPCE} \times \text{AM1.5G} \times 1000 / \text{IC}) d\lambda \quad (3)$$

where AM1.5G is the solar photon flux ( $\text{photons cm}^{-2}$ ),  $E_{\text{bg}}$  is the material bandgap (517 nm) and IC is  $6.241 \times 10^{18}$  electrons



per second. The solar to hydrogen conversion efficiency (STH) was then calculated by the following equation:

$$\text{STH}(\%) = \text{SPP}/81.3 \times 100 \quad (4)$$

where 81.3 in units of  $\text{mA cm}^{-2}$  is the theoretical photocurrent for complete conversion of the solar photon flux spectrum into a water splitting photocurrent.

Calculating AM1.5G photocurrents based on IPCE integration gives the same result as a photocurrent measured under solar simulated light when the measurements are conducted within a light intensity regime such that photocurrents change linearly with light intensity. For materials in which intensity-dependent recombination dominate, the photocurrent would increase non-linearly with light intensity. There is evidence in the literature that for moderate illumination intensities less than AM1.5G intensity, photocurrent densities do vary linearly with light intensity for  $\text{BiVO}_4$  and other metal oxides.<sup>77,78</sup> This method additionally prevents adverse effects such as heating of the device and electrolyte. The measurement of IPCE profiles additionally gives the user insights into properties such as photoabsorber bandgap and losses for photons with short wavelengths due to illumination through the glass backing of photoelectrodes. IPCE integration is also important to highlight as an acceptable route to enabling the use of more inexpensive lighting (that otherwise would have a spectrum incongruent with the solar spectrum), to give results that then may be rigorously compared to AM1.5 photocurrents reported in the literature.

## Data availability

The data that support the findings of this study are available in the tables presented in the study and in the ESI.†

## Author contributions

Conceptualization, B. T., J. N., and A. K.; investigation, B. T. and S. P.; project administration, B. T.; supervision, J. N. and A. K.; visualization, B. T.; writing – original draft, B. T.; writing – review & editing, B. T., S. P., J. N., A. K.

## Conflicts of interest

The authors declare no conflicts of interest.

## Acknowledgements

AK thanks the EPSRC for a Programme Grant (EP/W017075/1). BT thanks Imperial College for support *via* the President's PhD Scholarship. SDP thanks the Royal Society for a University Research Fellowship (URF\R1\191458) and Research Grant (RG\R2\232264). JN thanks the Royal Society for award of a Research Professorship and the European Research Council for funding *via* an Advanced Grant (CAPaCITY, grant no: 742708). We wish to acknowledge the use of the EPSRC funded Physical Sciences Data-science Service hosted by the University

of Southampton and STFC under grant number EP/S020357/1. Lee Tooley, Steve Atkins and Stefanos Karapanagiotidis are thanked for constructing and maintaining our chemical vapour deposition apparatus.

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